

09/914118

518 Rec'd PCT/PTO 23 AUG 2001

21. The following fees are submitted:

CALCULATIONS PTO USE ONLY

BASIC NATIONAL FEE (37 CFR 1.492 (a) (1) - (5)) :

- ☐ Neither international preliminary examination fee (37 CFR 1.482) nor international search fee (37 CFR 1.445(a)(2)) paid to USPTO and International Search Report not prepared by the EPO or JPO\$1000.00
- ☒ International preliminary examination fee (37 CFR 1.482) not paid to USPTO but International Search Report prepared by the EPO or JPO\$860.00
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- ☐ International preliminary examination fee paid to USPTO (37 CFR 1.482) but all claims did not satisfy provisions of PCT Article 33(1)-(4)\$690.00
- ☐ International preliminary examination fee paid to USPTO (37 CFR 1.482) and all claims satisfied provisions of PCT Article 33(1)-(4)\$100.00

ENTER APPROPRIATE BASIC FEE AMOUNT =

\$860.00

Surcharge of \$130.00 for furnishing the oath or declaration later than ☐ 20 ☐ 30 months from the earliest claimed priority date (37 CFR 1.492 (e)).

CLAIMS	NUMBER FILED	NUMBER EXTRA	RATE
Total claims	7 - 20 =	0	x \$18.00
Independent claims	1 - 3 =	0	x \$80.00

Multiple Dependent Claims (check if applicable). ☐**TOTAL OF ABOVE CALCULATIONS =**

0

Reduction of 1/2 for filing by small entity, if applicable. Verified Small Entity Statement must also be filed (Note 37 CFR 1.9, 1.27, 1.28) (check if applicable). ☐

SUBTOTAL =

\$860.00

Processing fee of \$130.00 for furnishing the English translation later than ☐ 20 ☐ 30 months from the earliest claimed priority date (37 CFR 1.492 (f)).

TOTAL NATIONAL FEE =

\$860.00

Fee for recording the enclosed assignment (37 CFR 1.21(h)). The assignment must be accompanied by an appropriate cover sheet (37 CFR 3.28, 3.31) (check if applicable). ☒

40.00

TOTAL FEES ENCLOSED =

\$900.00

Amount to be:
refunded \$
charged \$ 900.00

☐ A check in the amount of _____ to cover the above fees is enclosed.

☒ Please charge my Deposit Account No. 07-0832 in the amount of \$900.00 to cover the above fees.
A duplicate copy of this sheet is enclosed.

☒ The Commissioner is hereby authorized to charge any fees which may be required, or credit any overpayment to Deposit Account No. 07-0832 A duplicate copy of this sheet is enclosed.

NOTE: Where an appropriate time limit under 37 CFR 1.494 or 1.495 has not been met, a petition to revive (37 CFR 1.137(a) or (b)) must be filed and granted to restore the application to pending status.

SEND ALL CORRESPONDENCE TO:

Mr. Joseph S. Tripoli
THOMSON multimedia Licensing Inc.
Patent Department
PO Box 5312
Princeton, New Jersey 08540

SIGNATURE

FRANCIS A. DAVENPORT

NAME

36,316

REGISTRATION NUMBER

AUGUST 23, 2001

DATE

PCT INITIAL PROCESSING
AUG 27 2001

RECEIVED

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Gene Karl Sendelweck
Filed : February 4, 2000 - PCT National Phase of PCT/US00/03032
For : CONTROL OF SCANNING VELOCITY MODULATION

PRELIMINARY AMENDMENT

Hon. Commissioner of Patents and Trademarks
Box PCT
Washington, D.C. 20231

Sir:

In the US national phase application of PCT/US00/03032
please enter the following amendments.

IN THE SPECIFICATION (As Annexed to the International Preliminary
Examination Report:

Please amend the specification as follows:

Page 1, line 3, after the title, insert the following:

--This application claims the benefit under 35 U.S.C. § 365 of
International Application PCT/US00/03032, filed February 4, 2000, which
claims the benefit of U.S. Provisional Application No. 60/121,971, filed
February 26, 1999.--

IN THE CLAIMS (As Annexed to the International Preliminary Examination
Report:

1. A scanning velocity modulation deflection signal generator,
comprising:

a variable conduction device having a first input responsive
to a scanning velocity modulation deflection signal, and a second input
responsive to a control signal;

in a first condition said device providing a feedback path for controlling said scanning velocity modulation deflection signal in magnitude; and,

in a second condition said device interrupting said feedback path and inhibiting generation of said scanning velocity modulation deflection signal.

2. The scanning velocity modulation deflection signal generator of claim 1, wherein during said first condition said variable conduction device varies conduction in accordance with said magnitude of said scanning velocity modulating deflection signal.

3. The scanning velocity modulation deflection signal generator of claim 2, wherein said variable conduction device varies conduction to variably attenuate a scanning velocity modulating signal in accordance with said scanning velocity modulating deflection signal magnitude.

4. The scanning velocity modulation deflection signal generator of claim 1, wherein during said second condition said variable conduction device is fully conductive responsive to said control signal for inhibiting said scanning velocity modulation deflection signal.

5. The scanning velocity modulation deflection signal generator of claim 1, wherein during said second condition said variable conduction device is fully conductive, attenuating a scanning velocity modulating signal and inhibiting generation of said scanning velocity modulation deflection signal.

6. The scanning velocity modulation deflection signal generator of claim 1, wherein said second condition conduction in said variable conduction device is unresponsive to said scanning velocity modulating deflection signal.

7. The scanning velocity modulation deflection signal generator of claim 1, wherein said variable conduction device is a transistor.

REMARKS

The specification has been amended to include a reference to the priority application.

The above amendments to the claims have been made to eliminate reference indicia and to meet the requirements of the USPTO.

No fee is believed to have been incurred by virtue of this amendment. However, if a fee is incurred on the basis of this amendment, please charge such fee against deposit account 07-0832.

Respectfully submitted,

Gene Karl Sendelweck



Francis A. Davenport
Registration No. 36,316
609/734-9864

THOMSON multimedia Licensing Inc.
Patent Operation
PO Box 5312
Princeton, NJ 08543-5312

Date: August 23rd 2001.

MARKED UP CLAIMS

1. (AMENDED) A scanning velocity modulation deflection signal generator, comprising:

- a variable conduction device [(Q1)] having a first input [(Q1e)]
5 responsive to a scanning velocity modulation deflection signal [(Vm)], and a
second input [(Q1b)] responsive to a control signal;
in a first condition said device [(Q1)] providing a feedback path
[(Q1e-Q1c)] for controlling said [a] scanning velocity modulation deflection signal
[(Vm)] in magnitude; and,
10 in a second condition said device [(Q1)] interrupting said feedback
path [(Q1e-Q1c)] and inhibiting generation of said scanning velocity modulation
deflection signal [(Vm)].

2. (AMENDED) The scanning velocity modulation deflection signal generator
15 of claim 1, wherein during said first condition said variable conduction device
[(Q1)] varies conduction in accordance with said magnitude of said scanning
velocity modulating deflection signal [(Vm)].

3. (AMENDED) The scanning velocity modulation deflection signal generator
20 of claim 2, wherein said variable conduction device [(Q1)] varies conduction to
variably attenuate a scanning velocity modulating signal [(SVM)] in accordance
with said scanning velocity modulating deflection signal [(Vm)] magnitude.

4. (AMENDED) The scanning velocity modulation deflection signal generator
25 of claim 1, wherein during said second condition said variable conduction device
[(Q1)] is fully conductive responsive to said control signal for inhibiting said
scanning velocity modulation deflection signal [(Vm)].

5. (AMENDED) The scanning velocity modulation deflection signal generator of claim 1, wherein during said second condition said variable conduction device [(Q1)] is fully conductive, attenuating a scanning velocity modulating signal [(SVM)] and inhibiting generation of said scanning velocity modulation deflection
5 signal [(Vm)].

6. (AMENDED) The scanning velocity modulation deflection signal generator of claim 1, wherein said second condition conduction in said variable conduction device [(Q1)] is unresponsive to [of] said scanning velocity modulating deflection
10 signal [(Vm)].

7. (AMENDED) The scanning velocity modulation deflection signal generator of claim 1, wherein said variable conduction device [(Q1)] is a transistor.

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CONTROL OF SCANNING VELOCITY MODULATION

This invention relates to scanning velocity modulation (SVM) systems for enhancing picture sharpness and more particularly to a scanning velocity modulation control circuit integrated in an SVM system.

BACKGROUND OF THE INVENTION

It is well known that SVM systems may enhance cathode ray tube picture sharpness by modulating the scanning velocity of an electron beam based on a differentiated video signal, or SVM signal, derived from the luminance component of a video display signal. Slowing the scanning velocity of the electron beam causes a greater number of electrons to land at a particular point in the display resulting in a brighter picture at that particular location on the display. In contrast, increasing the velocity of the electron beam results in fewer electrons striking the display which leads to a darker picture at that particular location. The net effect of such modulation causes variations in display intensity about edge transitions in the picture resulting in the perception of increased picture sharpness. It is desirable, however, to disable SVM operation under certain conditions, for example, when channels are being changed, computer images displayed or when on screen display (OSD) message signals are generated for display. In addition, the output stages of an SVM circuit must be controlled to prevent over dissipation (excessive temperatures) in those stages.

Various schemes have been used to accomplish these objectives. For example, SVM systems are known which include a control circuit for protecting output stage devices and a disabling circuit for disabling an SVM circuit during OSD operation. It is also known to control SVM signal amplitude in accordance with output stage current to prevent excessive dissipation in output stage devices. Such systems, however, suffer from several disadvantages. However, SVM inhibition and the prevention of over dissipation are facilitated by separate, independent systems which leads to a greater number of components and increased costs.

Thus, what is needed is an SVM control circuit that accomplishes both of these important objectives through the use of a minimum number of components. Reducing the number of parts that is needed to successfully

operate an SVM system leads to lower costs.

SUMMARY OF THE INVENTION

A scanning velocity modulation deflection signal generator comprises a variable conduction device coupled to said scanning velocity modulation deflection signal generator. In a first condition the variable conduction device provides a feedback path to control a scanning velocity modulation deflection signal, and in a second condition the variable conduction device interrupts the feedback path and inhibits generation of the scanning velocity modulation deflection signal.

BRIEF DESCRIPTION OF THE DRAWINGS

FIGURE 1 is a block diagram of an SVM system employing an SVM circuit and including an inventive SVM control arrangement.

FIGURE 2 is a detailed circuit diagram of the SVM system of FIGURE 1.

FIGURE 3 is a circuit diagram of the SVM control circuit of FIGURE 2 with the SVM circuit of FIGURE 2 disabled and low output power at the output stage.

FIGURE 4 is a circuit diagram of the SVM control circuit of FIGURE 2 with the SVM circuit of FIGURE 2 enabled and low output power at the output stage.

FIGURE 5 is a circuit diagram of the SVM control circuit of FIGURE 2 with the SVM circuit of FIGURE 2 enabled and high output power at the output stage.

DETAILED DESCRIPTION

In FIGURE 1, a luminance video signal L is applied to SVM circuit 100 which generates an SVM deflection signal that modulates the speed of a scanning electron beam (not shown). SVM control circuit 200 controls SVM circuit 100 to prevent over dissipation in the output stages of SVM circuit 100 and enables or disables SVM circuit 100 when it senses a display condition not requiring SVM display enhancement. More specifically, luminance video signal L enters amplifier stage 1 which is coupled to differentiator circuit 2 whereby luminance video signal L is amplified and differentiated. Next, the differentiated

video signal, or SVM signal, is applied to delay stage 3 where it passes through all pass equalizers 1 and 2. Delay stage 3 delays the SVM signal to provide synchronization at output stage 8 with its corresponding displayed luminance signal. Once the SVM signal has been delayed, it enters limiting amplifier stage 4 which amplifies the SVM signal and limits its peak-to-peak voltage to protect downstream components. The SVM signal is then applied to pre-driver stage 5 which drives output stage 8 and provides noise coring. Driver 6 then converts the SVM signal into a SVM deflection signal that is used to drive SVM coil 7.

Variable conduction switch 9 is coupled to SVM circuit 100 at the input of limiting amplifier stage 4 and at the output of driver 6 in output stage 8. Variable conduction switch 9 can operate as a variable conductance device to control SVM signal amplitude responsive to control signal CS1 thereby preventing over dissipation in output stage 8 by diverting a portion of the SVM signal from circuit 100 to ground. In addition, variable conduction switch 9 is controlled by control signal CS2 which enables or disables SVM circuit 100. When control circuitry 10 determines an SVM OFF or non-SVM enhancement condition, for example, a channel change, input signal selection or OSD message insertion, control block 10 changes the state of the SVM ON/OFF control signal. With the termination of the SVM OFF or non-SVM enhancement condition SVM ON/OFF state is toggled and reestablishes SVM circuit 100 operation, restoring feed back control of output power dissipation. A switch SW1 is depicted with a dotted outline to denote that the switching function can be facilitated within controller 10 or by means of an external switching device.

FIGURE 2 illustrates the circuitry of FIGURE 1, including a detailed embodiment of SVM circuit 100 and SVM control circuit 200. In FIGURE 2, luminance video signal L is amplified by transistor Q2 and differentiated in the collector circuit by inductor L1. The emitter electrode of transistor Q2 is coupled to ground via resistor R7 and the collector is coupled through resistor R8 to a source of operating potential +VA, for example, 12 volts. Operating potential +VA is decoupled by resistor R9 in series with decoupling capacitor C4. The collector electrode of transistor Q2 is also coupled to the base electrode of transistor Q3. Transistor Q3, capacitor C5, inductor L2 and resistors R11 and

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R12 form the first of complementary all pass equalizers 1 and 2 with transistor Q4, capacitor C6, inductor L3 and resistors R14 and R15 forming the second. The output of all pass equalizer 1 is coupled to the base electrode of transistor Q4. All pass equalizers 1 and 2 combine to form delay stage 3 which delays the SVM signal by 270 ns to compensate for the delay introduced into the SVM signal's corresponding luminance component by the luminance processing circuitry (not pictured). The emitter electrode of transistor Q3 is coupled to supply voltage +VA through resistor R10, and the collector electrode of transistor Q4 is coupled to supply voltage +VA through resistor R13. Power supply +VA is further decoupled by resistor R32 in series with decoupling capacitor C6.

The output of all pass equalizer 2 is AC coupled through capacitor C7 to the base electrode of transistor Q5 which operates as a high-gain limiting amplifier. Resistor R16 sets the bias for the transistor. Limiting amplifier stage 4 limits the peak-to-peak voltage of the SVM signal thus providing extra protection for successive transistors in SVM circuit 100. Transistor Q1 is AC coupled via capacitor C3 to the input of limiting amplifier stage 4 and, as will be further explained in greater detail, provides negative feedback to prevent over dissipation in output stage 8 and in addition acts as an on/off or inhibit switch for SVM circuit 100. The collector electrode of transistor Q5 is coupled to supply voltage +VA through resistor R18 and is also coupled to the input of pre-driver stage 5. Bypass capacitor C8 in conjunction with resistor R17 provides increased voltage gain as the frequency of the SVM signal increases.

Pre-driver stage 5 includes complementary type, emitter follower transistors Q6 and Q7 with the base electrode of Q6 coupled to the base electrode of Q7, both base electrodes coupled to the collector electrode of transistor Q5. The emitter electrode of Q6 is coupled via resistor R19 to the emitter electrode of transistor Q7. Transistors Q6 and Q7 form a Class B amplifier which operates to drive output stage 8 and additionally provides noise coring, that is, only SVM signals greater in magnitude than approximately ± 0.7 volts are coupled because of the Class B configuration which in turn causes low-level noise components to be removed from the SVM signal.

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The output of pre-driver stage 5 is AC coupled through capacitors C10 and C11 to the base electrodes of transistors Q8 and Q9, with resistor R20 and capacitor C12 filtering the output to reduce RFI. The emitter electrode of transistor Q8 is directed through resistor R26 to a relatively high source of operating potential, +VB, generally ranging from 120-180 volts. Supply voltage +VB is decoupled by resistor R25 in series with decoupling capacitor C9. Resistors R21, R22, R23 and R24 form a series connected potential divider coupled between supply voltage +VB and ground. Transistors Q8 and Q9 operate as a Class B amplifier with the bases biased at cut off by the resistive divider R21, R22, R23 and R24. Resistor R26 and R27 set the turn on voltage for transistors Q8 and Q9 respectively and limit power dissipation in output stage 8. Resistor R28 and capacitor C13 are coupled to the emitter electrode of transistor Q8, and, similarly, resistor R29 and capacitor C16 are coupled to the emitter electrode of transistor Q9. These feedback paths are configured to circulate pulse current mainly within output stage 8 to limit unwanted, extraneous crosstalk components. When transistor Q8 is on, current flows through R28, C13, and SVM coil 7 to generate the necessary deflection field for one polarity of scanning velocity modulation. Conversely, when transistor Q9 is on, current flow through R29, C16, and SVM coil 7 generates the deflection field of the opposite polarity. To prevent unwanted resonance in SVM coil 7, resistor R30 and capacitor C15 are coupled in shunt with the coil. Clamping diodes D1 and D2 prevent the peak-to-peak ratings of transistors Q8 and Q9 from being exceeded, and ferrite beads located on the collector electrodes of transistors Q8 and Q9 aid in limiting spurious radiation in output stage 8.

The collector electrode of transistor Q1 is AC coupled via capacitor C3 to the input of limiting amplifier stage 4, and the emitter electrode is coupled via resistor R31 to output stage 8 at the junction of resistor R29 and capacitor C16. The emitter electrode is also coupled to supply voltage +VA through resistor R6 which supplies a current source for transistor Q1. Capacitor C2 is coupled to the emitter electrode and together with resistor R31 forms a lowpass filter for filtering high frequency components and noise from SVM coil driver stage 8. High output power due to high SVM deflection signal levels in output

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stage 8 results in high current flow through resistor R27 which causes the voltage at the emitter of transistor Q1 to rise. Transistor Q1 turns on and will conduct a portion of the SVM signal at the input of limiting amplifier stage 4 through C3 and C2 to ground. This action forms a negative feedback loop which leads to a reduction in the level of the SVM deflection signal and, accordingly, the power level in output stage 8 and consequently lowers the voltage at the emitter of transistor Q1. Depending on the level of output power, transistor Q1 may achieve steady state operation or enter the cut off stage. If output power continues to increase, the voltage at the emitter will continue to rise and transistor Q1 will accordingly divert a greater amount of the SVM signal through capacitors C3 and C2 to ground thus preventing over dissipation in output stage 8. The values of resistors R6 and R31 are chosen to control the maximum permissible temperature of the output devices in output stage 8, and the value of resistor R5 is chosen to attenuate the SVM signal level symmetrically.

The base electrode of transistor Q1 is coupled through resistors R1, R2, R4 and R5 to a source of operating potential +VC, typically 5 volts. Resistors R1, R2, R3 and R4 form a potential divider which, in conjunction with resistor R5, partially determines the current in the base of transistor Q1. Capacitor C1 is coupled to a point between resistors R5 and R4 to provide decoupling and prevent inadvertent switching of transistor Q1. Control circuitry 10 detects display conditions in which SVM action is inhibited, for example during a channel change, input selection or OSD message insertion. Control circuitry 10 can be any switchable logic or control circuitry. For example, the display control microprocessor, controls operation of the display device and can identify operational conditions requiring SVM inhibition. Furthermore controller 10 can provide a switching function, for example providing a grounded, low impedance condition or a high impedance condition, as depicted by switch SW 1 or can output a suitable control signal, SVM ON/OFF, for enabling or disabling a physical switching device SW 1. According to a preferred embodiment, control circuitry 10 is a microprocessor. In normal operation, that is, when controller 10 does not detect an SVM inhibit condition, controller 10 outputs SVM ON/OFF control signal with a high impedance condition. The SVM ON/OFF control signal

can be directly coupled, as shown, to the junction of resistors R1 and R2, or may be coupled to control a physical switching device SW 1. Thus with the SVM ON/OFF signal in a high impedance condition, or switch SW 1 is open, the bias voltage from +VC is applied to the base of transistor Q1 via potential divider
5 formed by resistors R1, R2, R4, and R3. If the power dissipation in output stage 8 is low, transistor Q1 remains in cut off and the SVM signal at transistor Q5 base is unaffected.

When control circuitry 10 detects an SVM inhibit condition, controller 10 changes the state of the SVM ON/OFF control signal which
10 becomes a low impedance to ground. Thus the SVM ON/OFF signal can directly ground the junction of resistors R1 and R2, or close switch SW 1, resulting in the base voltage of transistor Q1 being pulled low. As a result, transistor Q1 turns on and conducts the SVM signal through capacitor C3 and C2 and, to a lesser extent C1, to ground thus substantially removing the SVM signal from the
15 base of transistor Q5 and inhibiting SVM action. Once the SVM off condition terminates, the SVM ON/OFF signal reverts to a high impedance condition effectively opening switch SW 1 and allowing the voltage at the base of transistor Q1 rise and, so long as output power remains low, transistor Q1 remains off.

20 FIGURE 3 depicts the operation of SVM control system 200 when output power is low and SVM ON/OFF is a low impedance, or switch SW 1 is closed. Because the base voltage of transistor Q1 is low, transistor Q1 turns on and couples the SVM signal from the input of the limiting amplifier transistor Q5 through capacitors C3 and C2 or C1 to ground. This inhibits SVM operation in
25 SVM circuit 100 during computer image display, channel change or OSD message display. FIGURE 4 illustrates the normal operation of SVM control circuit 200. Output power remains low, and switch SW 1 is now open thus allowing a higher biasing voltage to be applied to the base of transistor Q1. Because output power is low, the voltage at the emitter is not high enough to
30 turn on transistor Q1 and, the SVM circuit is enabled. In FIGURE 5, switch SW 1 is open and the SVM circuit is operational. High output power in output stage 8 causes an increase in current flow through resistor R27, and the voltage at the

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emitter of transistor Q1 starts to rise. Eventually, transistor Q1 turns on and begins to variably conduct current from the input of transistor Q5 through capacitors C3 and C2 to ground. As the voltage at the emitter of transistor Q1 continues to rise, the transistor will conduct an even greater amount of current

5 from SVM circuit 100 to ground.

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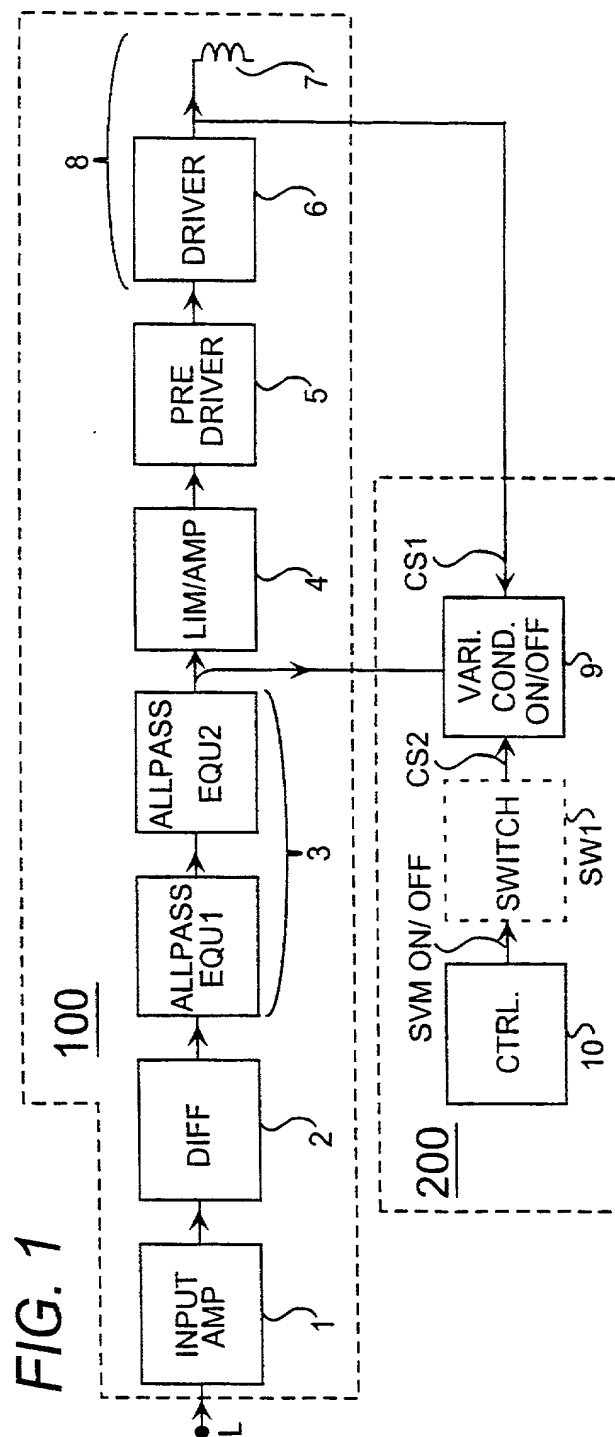
CLAIMS

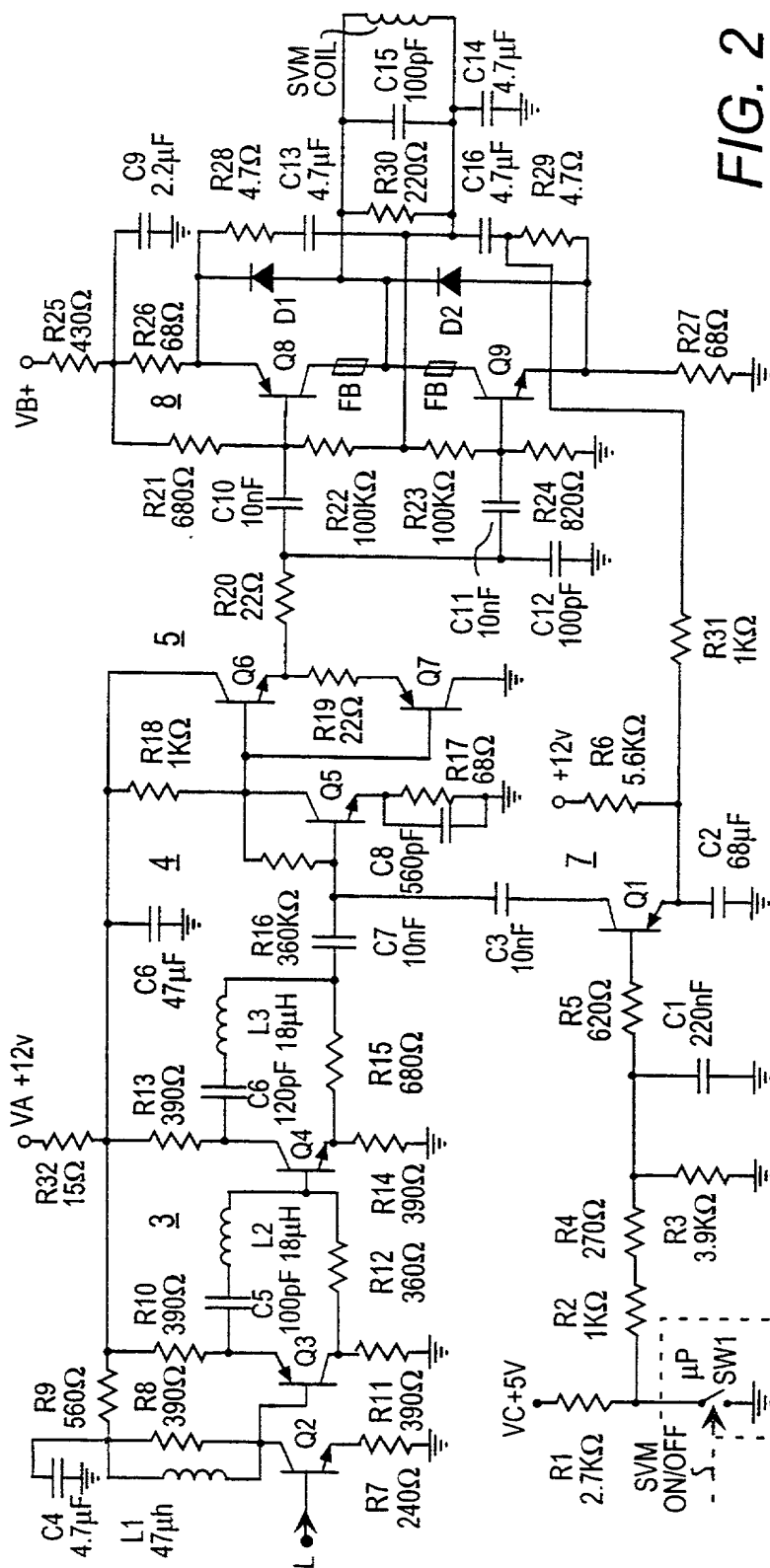
1. A scanning velocity modulation deflection signal generator, comprising: a variable conduction device coupled to said scanning velocity modulation deflection signal generator, and in a first condition providing a feedback path to control a scanning velocity modulation deflection signal, and in a second condition interrupting said feedback path and inhibiting generation of said scanning velocity modulation deflection signal.
2. The scanning velocity modulation deflection signal generator of claim 1, wherein during said first condition said variable conduction device varies conduction in accordance with a magnitude of said scanning velocity modulating deflection signal.
3. The scanning velocity modulation deflection signal generator of claim 2, wherein said variable conduction device varies conduction to variably attenuate a scanning velocity modulating signal in accordance with said scanning velocity modulating deflection signal magnitude.
4. The scanning velocity modulation deflection signal generator of claim 1, wherein during said second condition said variable conduction device is fully conductive responsive to a scanning velocity modulation inhibit signal.
5. The scanning velocity modulation deflection signal generator of claim 1, wherein during said second condition said variable conduction device is fully conductive, attenuating a scanning velocity modulating signal and inhibiting generation of said scanning velocity modulation deflection signal.

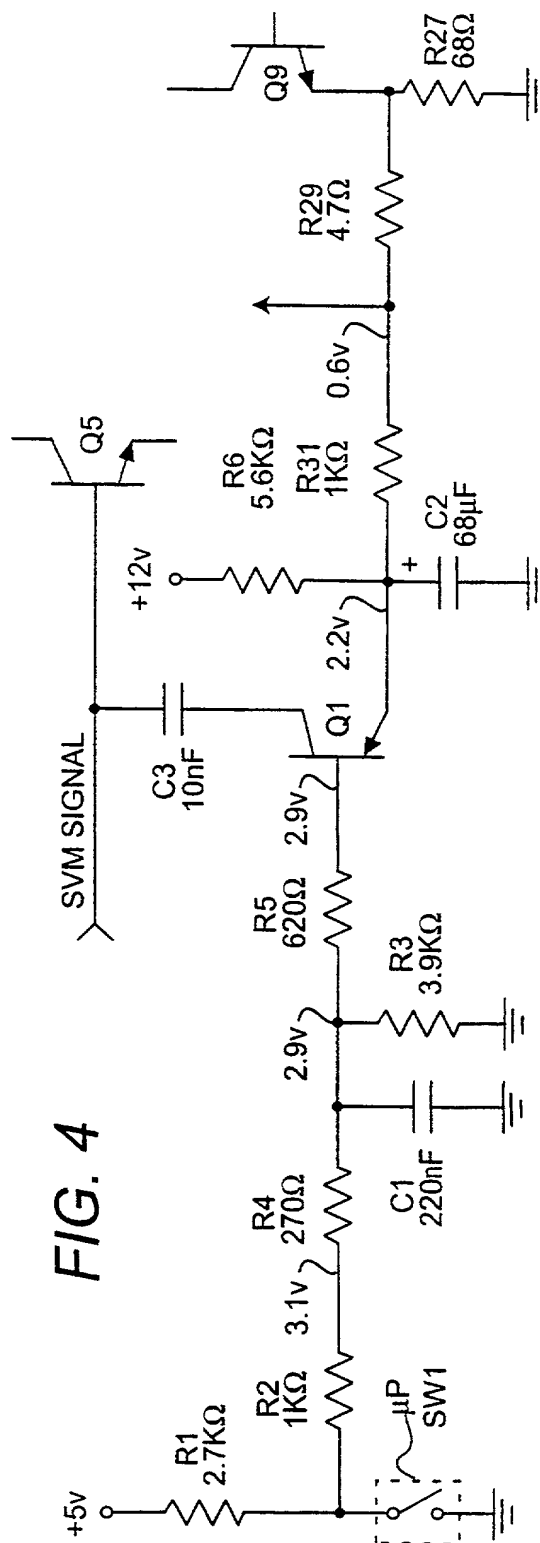
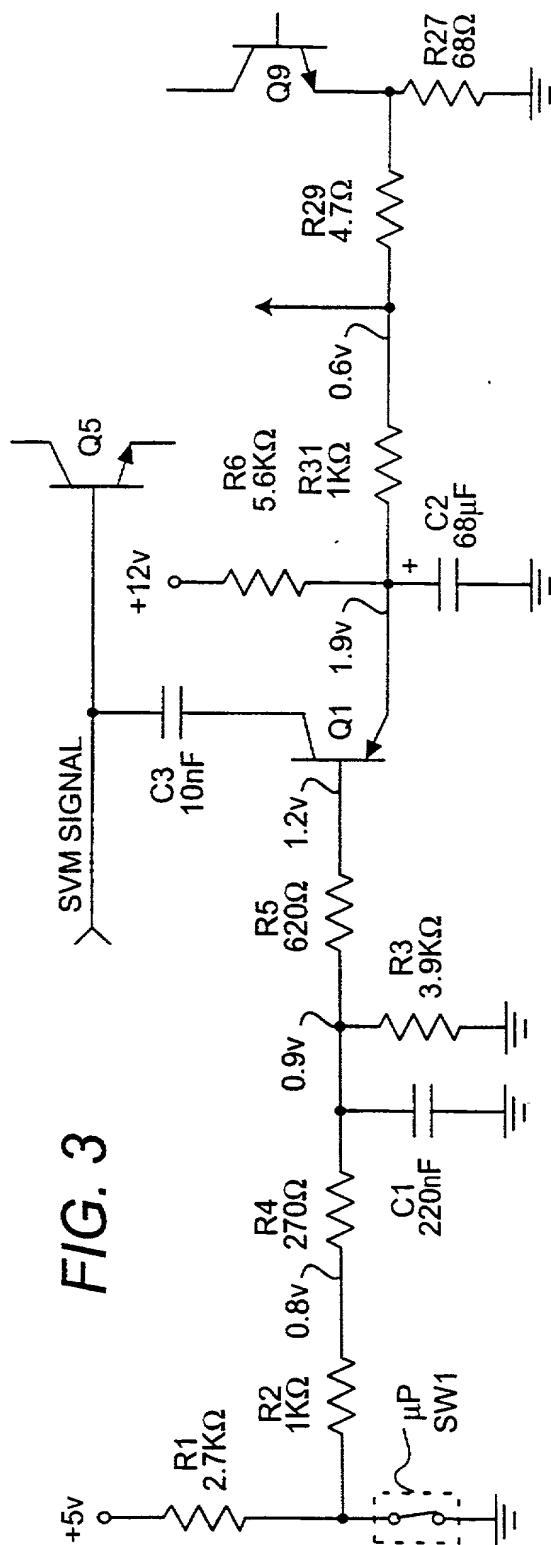
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6. The scanning velocity modulation deflection signal generator of claim 1, wherein during said second condition said variable conduction device is a fully conductive, independently of said scanning velocity modulating deflection signal.

7. The scanning velocity modulation deflection signal generator of claim 1,
5 wherein said variable conduction device is a transistor.







[illegible]

FIG. 5

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PTO/SB/01 (10-00)

Approved for use through 10/31/2002. OMB 0651-0032
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**DECLARATION FOR UTILITY OR
DESIGN
PATENT APPLICATION
(37 CFR 1.63)**

☒ Declaration
Submitted With Initial
Filing **OR** ☐ Declaration
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Filing (surcharge
(37 CFR 1.16 (e))
required)

Attorney Docket Number RCA 89226

First Named Inventor Gene Karl Sendelweck

COMPLETE IF KNOWN

Application Number /

Filing Date Herewith

Group Art Unit

Examiner Name

As a below named inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

CONTROL OF SCANNING VELOCITY MODULATION

the specification of which (Title of the Invention)

☐ is attached hereto

OR

☒ was filed on (MM/DD/YYYY) **02/04/2000** as United States Application Number or PCT International

Application Number **PCT/US00/03032** and was amended on (MM/DD/YYYY) **02/13/2001** (if applicable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims as amended specifically referred to above.

I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR 1.56, including for continuation-in-part applications, material information which became available between the filing date of the prior application and the national or PCT international filing date of the continuation-in-part application.

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 365(a) of any PCT international application which designated at least one country other than the United States of America, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or of any PCT international application having a filing date before that of the application on which priority is claimed.

Prior Foreign Application Number(s)	Country	Foreign Filing Date (MM/DD/YYYY) Country	Priority Not Claimed	Certified Copy Attached?	
				YES	NO
			<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
			<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
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☐ Additional foreign application numbers are listed on a supplemental priority data sheet PTO/SB/02B attached hereto:

I hereby claim the benefit under 35 U.S.C. 119(e) of any United States provisional application(s) listed below.

Application Number(s)	Filing Date (MM/DD/YYYY)	<input type="checkbox"/> Additional provisional application numbers are listed on a supplemental priority data sheet PTO/SB/02B attached hereto.
60/121,971	02/26/1999	

[Page 1 of 2]

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DECLARATION — Utility or Design Patent Application

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Name	JOSEPH S. TRIPOLI		
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PRINCETON	NJ	08543-5312	
Country	Telephone	Fax	
USA	(609) 734 - 9443	(609) 734 - 9700	

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

NAME OF SOLE OR FIRST INVENTOR: ☐ A petition has been filed for this unsigned inventor

Given Name	Family Name or Surname
GENE KARL	SENDELWECK

Inventor's Signature	Date
<i>Gene Karl Sendelweck</i>	Aug. 7, 2001

Residence: City	State	Country	Citizenship
Indianapolis	Indiana	Marion	US

Mailing Address 5415 East 72nd Street

Mailing Address

City	State	ZIP	Country
Indianapolis	Indiana	46250	U.S.A.

NAME OF SECOND INVENTOR: ☐ A petition has been filed for this unsigned inventor

Given Name	Family Name or Surname

Inventor's Signature	Date

Residence: City	State	Country	Citizenship

Mailing Address

Mailing Address

City	State	ZIP	Country

☐ Additional inventors are being named on the _____ supplemental Additional Inventor(s) sheet(s) PTO/SB/02A attached hereto.

FOE230" 2771660